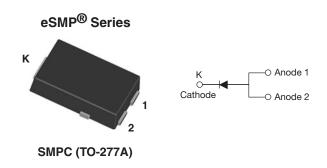


# Hyperfast Rectifier, 8 A FRED Pt®



#### **LINKS TO ADDITIONAL RESOURCES**



PRIMARY CHARACTERISTICS				
I <sub>F(AV)</sub>	8 A			
$V_{R}$	600 V			
V <sub>F</sub> at I <sub>F</sub>	1.13 V			
t <sub>rr (typ.)</sub>	33 ns			
T <sub>J</sub> max.	175 °C			
Package	SMPC (TO-277A)			
Circuit configuration	Single			

#### **FEATURES**

Hyperfast recovery time, reduced Q<sub>rr</sub>, and soft recovery



RoHS

COMPLIANT

HALOGEN FREE

- 175 °C maximum operating junction temperature
- For PFC, CRM/CCM, snubber operation
- Low forward voltage drop
- Low forward voltage (
- · Low leakage current
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Meets JESD 201 class 2 whisker test
- AEC-Q101 qualified
- Material categorization: for definitions of compliance please see <a href="https://www.vishay.com/doc?99912"><u>www.vishay.com/doc?99912</u></a>

#### **DESCRIPTION / APPLICATIONS**

State of the art hyperfast recovery rectifiers specifically designed with optimized performance of forward voltage drop and hyperfast recovery time.

The planar structure and the platinum doped life time control guarantee the best overall performance, ruggedness, and reliability characteristics.

These devices are intended for use in PFC, boost, lighting, in the AC/DC section of SMPS, freewheeling and clamp diodes.

The extremely optimized stored charge and low recovery current minimize the switching losses and reduce power dissipation in the switching element.

### **MECHANICAL DATA**

Case: SMPC (TO-277A)

Molding compound meets UL 94 V-0 flammability rating Halogen-free, RoHS-compliant

Terminals: matte tin plated leads, solderable per

J-STD-002

ABSOLUTE MAXIMUM RATINGS				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Peak repetitive reverse voltage	$V_{RRM}$		600	V
Average rectified forward current	I <sub>F(AV)</sub>	T <sub>Sp</sub> = 136 °C	8	Λ
Non-repetitive peak surge current	I <sub>FSM</sub>	T <sub>J</sub> = 25 °C	90	A
Operating junction and storage temperatures	T <sub>J</sub> , T <sub>Stg</sub>		-55 to +175	°C

<b>ELECTRICAL SPECIFICATIONS</b> (T <sub>J</sub> = 25 °C unless otherwise specified)						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Breakdown voltage, blocking voltage	$V_{BR}$ , $V_{R}$	I <sub>R</sub> = 100 μA	600	-	-	
Forward voltage V <sub>F</sub>	W	I <sub>F</sub> = 8 A	-	1.36	1.91	V
	VF	I <sub>F</sub> = 8 A, T <sub>J</sub> = 150 °C	-	1.13	1.67	
Reverse leakage current		$V_R = V_R$ rated	-	-	5	
	I <sub>R</sub>	T <sub>J</sub> = 150 °C, V <sub>R</sub> = V <sub>R</sub> rated	-	50	300	μΑ
Junction capacitance	C <sub>T</sub>	V <sub>R</sub> = 600 V	-	8	-	pF



<b>DYNAMIC RECOVERY CHARACTERISTICS</b> (T <sub>J</sub> = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNITS
		$I_F = 1 A, dI_F/dt$	$= 50 \text{ A/}\mu\text{s}, \text{ V}_{\text{R}} = 30 \text{ V}$	ı	33	-	
Reverse recovery time	+	$I_F = 0.5 A, I_R =$	1 A, I <sub>rr</sub> = 0.25 A	-	-	40	no
heverse recovery time	t <sub>rr</sub>	T <sub>J</sub> = 25 °C		-	44	-	ns
		T <sub>J</sub> = 125 °C		-	81	-	
Peak recovery current I <sub>RRM</sub>	1	T <sub>J</sub> = 25 °C	$I_F = 8 A$	-	7	-	۸
	T <sub>J</sub> = 125 °C	dI <sub>F</sub> /dt = 500 A/μs V <sub>R</sub> = 400 V	-	11.5	-	A	
Davieres resolvent charge	0	T <sub>J</sub> = 25 °C		-	153	-	nC
Reverse recovery charge	Q <sub>rr</sub>	T <sub>J</sub> = 125 °C		-	460	-	110

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Maximum junction and storage temperature range	T <sub>J</sub> , T <sub>Stg</sub>		-55	-	175	°C
Thermal resistance, junction to mount	$R_{thJM}$		-	2.4	3.5	°C/W
Approximate weight				0.1	•	g
Marking device		Case style SMPC (TO-277A)		QE	H6	

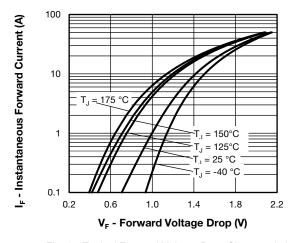


Fig. 1 - Typical Forward Voltage Drop Characteristics

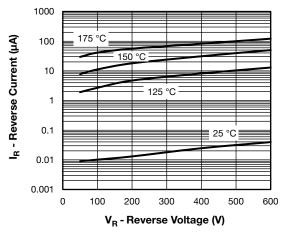


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

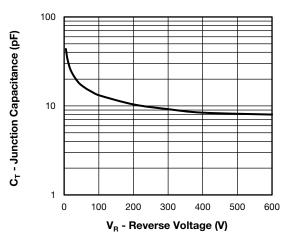


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

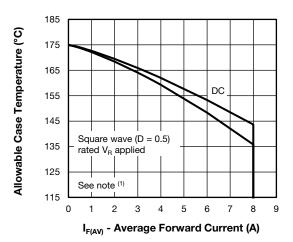


Fig. 4 - Maximum Allowable Case Temperature vs. Average Forward Current

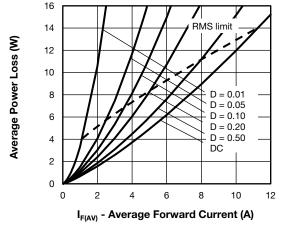


Fig. 5 - Forward Power Loss Characteristics

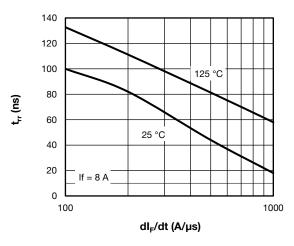


Fig. 6 - Typical Reverse Recovery Time vs. dl<sub>F</sub>/dt

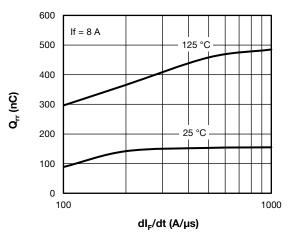


Fig. 7 - Typical Stored Charge vs. dl<sub>F</sub>/dt

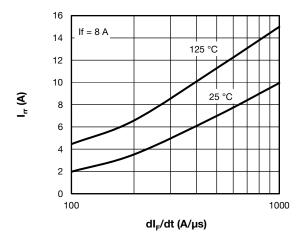
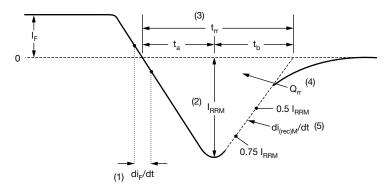


Fig. 8 - Typical Reverse Recovery Current vs. dl<sub>F</sub>/dt

#### Note

 $^{(1)} \mbox{ Formula used: } T_{C} = T_{J} - (Pd + Pd_{REV}) \mbox{ } x \mbox{ } R_{thJC}; Pd = \mbox{ forward power loss } = I_{F(AV)} \mbox{ } x \mbox{ } V_{FM} \mbox{ } at \mbox{ } (I_{F(AV)}/D) \mbox{ } (see \mbox{ fig. 5}); \\ Pd_{REV} = \mbox{ inverse power loss } = V_{R1} \mbox{ } x \mbox{ } I_{R} \mbox{ } (1 - D); I_{R} \mbox{ } at \mbox{ } V_{R1} = \mbox{ rated } V_{R}$ 

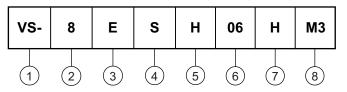


- (1) di<sub>F</sub>/dt rate of change of current through zero crossing
- (4)  $Q_{rr}$  area under curve defined by  $t_{rr}$  and  $I_{RRM}$
- (2) I<sub>RRM</sub> peak reverse recovery current
- $Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$
- (3) t<sub>rr</sub> reverse recovery time measured from zero crossing point of negative going I<sub>F</sub> to point where a line passing through 0.75 I<sub>RRM</sub> and 0.50 I<sub>RRM</sub> extrapolated to zero current.
- (5) di<sub>(rec)M</sub>/dt peak rate of change of current during t<sub>b</sub> portion of t<sub>rr</sub>

Fig. 9 - Reverse Recovery Waveform and Definitions

#### **ORDERING INFORMATION TABLE**

**Device code** 



- Vishay Semiconductors product
- 2 Current rating (8 = 8 A)
- 3 Circuit configuration:

E = single diode

4 - S = SMPC package

**5** - Process type,

H = hyper fast recovery

6 - Voltage code (06 = 600 V)

7 - H = AEC-Q101 qualified

8 - M3 = halogen-free, RoHS-compliant, and terminations lead (Pb)-free

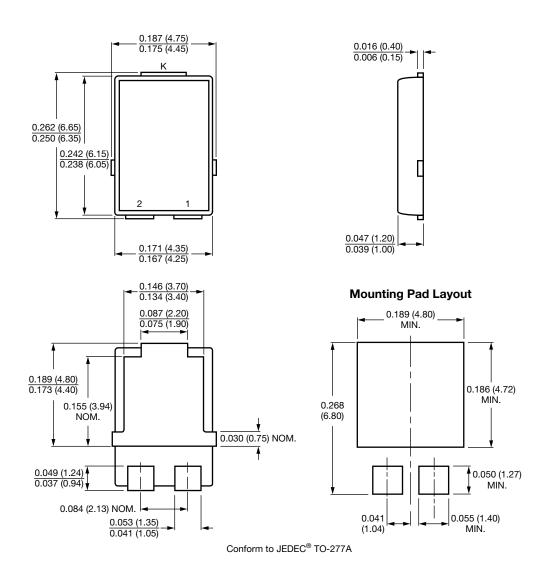
ORDERING INFORMATION (Example)					
PREFERRED P/N	QUANTITY PER REEL	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION		
VS-8ESH06HM3/H	1500	1500	7" diameter plastic tape and reel		
VS-8ESH06HM3/I	6500	6500	13" diameter plastic tape and reel		

LINKS TO RELATED DOCUMENTS				
Dimensions	www.vishay.com/doc?95570			
Part marking information	www.vishay.com/doc?95565			
Packaging information	www.vishay.com/doc?88869			
SPICE model	www.vishay.com/doc?97330			



# **SMPC (TO-277A)**

### **DIMENSIONS** in inches (millimeters)





## **Legal Disclaimer Notice**

Vishay

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